

ZXTN25100DZ100V NPN high gain transistor in SOT89

Summary

BV_{CEX} > 180V

 $BV_{CEO} > 100V$

 $BV_{ECO} > 6V$

 $I_{C(cont)} = 2.5A$

V_{CE(sat)} < 100mV @ 1A

 $R_{CE(sat)} = 80 m\Omega$

 $P_{D} = 2.4W$

Complementary part number ZXTP25100CZ

Description

Packaged in the SOT89 outline this new low saturation NPN transistor offers extremely low on state losses making it ideal for use in DC-DC circuits and various driving and power management functions.

Features

- High power dissipation SOT89 package
- High gain
- · Low saturation voltage
- 180V forward blocking voltage
- · 6V reverse blocking voltage

Applications

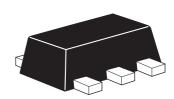
- · PSU start up switch
- DC DC converters
- · Motor drive
- · Relay, lamp and solenoid drive

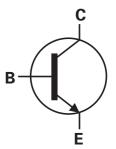
Ordering information

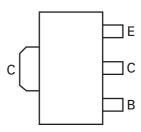
Device	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN25100DZTA	7	12	1000

Device marking

1K9







Pinout - top view

Absolute maximum ratings

Parameter	Symbol	Limit	Unit
Collector-Base voltage	V _{CBO}	180	V
Collector-Emitter voltage (forward blocking)	V _{CEX}	180	V
Collector-Emitter voltage	V _{CEO}	100	V
Emitter-Collector voltage (reverse blocking)	V _{ECO}	6	V
Emitter-Base voltage	V _{EBO}	7	V
Continuous Collector current ^(c)	I _C	2.5	Α
Base current	I _B	1	Α
Peak pulse current	I _{CM}	3.5	Α
Power dissipation at T _A =25°C ^(a)	P _D	1.1	W
Linear derating factor		8.8	mW/°C
Power dissipation at T _A =25°C ^(b)	P _D	1.8	W
Linear derating factor		14.4	mW/°C
Power dissipation at T _A =25°C ^(c)	P _D	2.4	W
Linear derating factor		19.2	mW/°C
Power dissipation at T _A =25°C ^(d)	P _D	4.46	W
Linear derating factor		35.7	mW/°C
Power dissipation at T _C =25°C ^(e)	P _D	19.2	W
Linear derating factor		153	mW/°C
Operating and storage temperature range	T _j , T _{stg}	-55 to +150	°C

Thermal resistance

Parameter	Symbol	Limit	Unit
Junction to ambient ^(a)	$R_{\Theta JA}$	117	°C/W
Junction to ambient ^(b)	$R_{\Theta JA}$	68	°C/W
Junction to ambient ^(c)	$R_{\Theta JA}$	51	°C/W
Junction to ambient ^(d)	$R_{\Theta JA}$	28	°C/W
Junction to case ^(e)	$R_{\Theta JC}$	7.95	°C/W

NOTES:

⁽a) For a device surface mounted on 15mm x 15mm x 0.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

⁽b) Mounted on 25mm x 25mm x 0.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

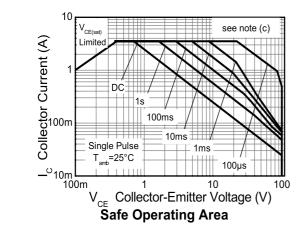
⁽c) Mounted on 50mm x 50mm x 0.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions.

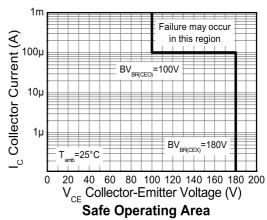
⁽d) As (c) above measured at t<5 seconds.

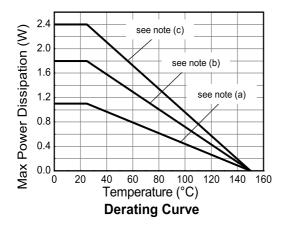
⁽e) Junction to case (collector tab). Typical

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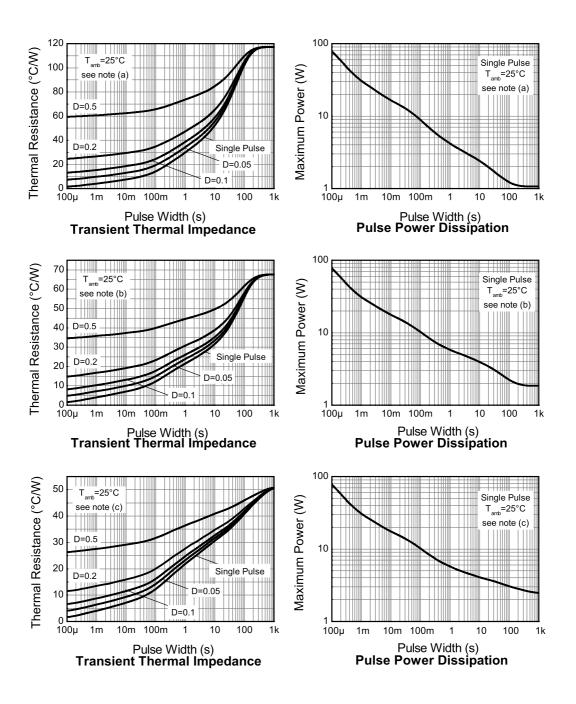
Thermal characteristics







Thermal characteristics



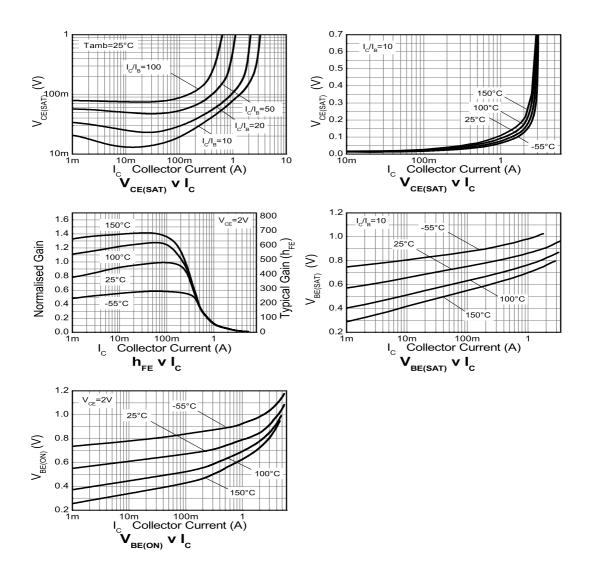
Electrical characteristics (at T_{amb} = 25°C unless otherwise stated)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-Base breakdown voltage	BV _{CBO}	180	220		V	I _C = 100μA
Collector-Emitter breakdown voltage (forward blocking)	BV _{CEX}	180	220		V	I_C = 100μA, R_{BE} < 1kΩ or -1V > V_{BE} > 0.25V
Collector-Emitter breakdown voltage	BV _{CEO}	100	130		V	I _C = 10mA ^(*)
Emitter-Collector breakdown voltage (reverse blocking)	BV _{ECX}	6	8.2		V	I_E = 100μA, R_{BC} < 1kΩ or 0.25V > V_{BC} > -0.25V
Emitter-Collector breakdown voltage (reverse blocking)	BV _{ECO}	6	8.7		V	l _E = 100μA
Emitter-Base breakdown voltage	BV _{EBO}	7	8.3		V	I _E = 100μA
Collector-Base cut-off current	I _{CBO}		<1	50 0.5	nA μA	$V_{CB} = 180V$ $V_{CB} = 180V, T_{amb} = 100$ °C
Collector-Emitter cut-off current	I _{CEX}			100	nA	$V_{CE} = 100V, R_{BE} < 1k\Omega$ or $-1V < V_{BE} < 0.25V$
Emitter cut-off current	I _{EBO}		<1	50	nA	V _{EB} = 5.6V
Collector-Emitter	V _{CE(sat)}		120	170	mV	$I_C = 0.5A$, $I_B = 10mA^{(*)}$
saturation voltage			80	100	mV	$I_C = 1A$, $I_B = 100 \text{mA}^{(*)}$
			220	345	mV	$I_C = 2.5A$, $I_B = 250mA^{(*)}$
Base-Emitter saturation voltage	V _{BE(sat)}		935	1000	mV	$I_C = 2.5A$, $I_B = 250 \text{mA}^{(*)}$
Base-Emitter turn-on voltage	V _{BE(on)}		890	950	mV	$I_C = 2.5A, V_{CE} = 2V^{(*)}$
Static forward current transfer ratio	h _{FE}	300 120 40	450 170 60 20	900		$I_{C} = 10 \text{mA}, V_{CE} = 2V^{(*)}$ $I_{C} = 0.5 \text{A}, V_{CE} = 2V^{(*)}$ $I_{C} = 1 \text{A}, V_{CE} = 2V^{(*)}$ $I_{C} = 2.5 \text{A}, V_{CE} = 2V^{(*)}$
Transition frequency	f _T		175		MHz	I _C = 50mA, V _{CE} = 10V f = 100MHz
Input capacitance	C _{ibo}		154	250	pF	V _{EB} = 0.5V, f = 1MHz ^(*)
Output capacitance	C _{obo}		8.7	15	pF	V _{CB} = 10V, f = 1MHz ^(*)
Delay time	t _d		16.4		ns	
Rise time	t _r		115		ns	$I_C = 500 \text{mA}, V_{CC} = 10 \text{V},$
Storage time	t _s		763		ns	$I_{B1} = -I_{B2} = 50 \text{mA}$
Fall time	t _f		158		ns	1

NOTES:

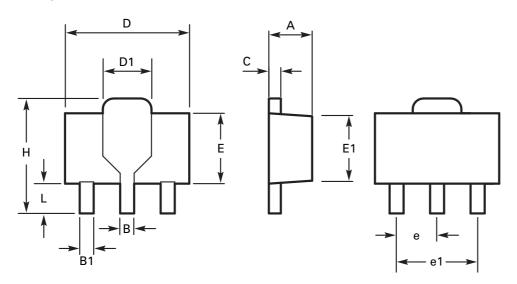
(*)Measured under pulsed conditions. Pulse width $\leq 300 \mu s;$ duty cycle $\leq 2\%.$

Typical characteristics



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Package outline - SOT89



DIM	Millin	neters	Inc	hes	DIM	Millimeters		Inches	
	Min	Max	Min	Max		Min	Max	Min	Max
Α	1.40	1.60	0.550	0.630	Е	2.29	2.60	0.090	0.102
В	0.44	0.56	0.017	0.022	E1	2.13	2.29	0.084	0.090
B1	0.36	0.48	0.014	0.019	е	1.50 BSC		0.059 BSC	
С	0.35	0.44	0.014	0.017	e1	3.00 BSC		0.118 BSC	
D	4.40	4.60	0.173	0.181	Н	3.94	4.25	0.155	0.167
D1	1.52	1.83	0.064	0.072	L	0.89	1.20	0.035	0.047

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

ZXTN25100DZ

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